



Low-Voltage, CMOS Analog Multiplexers/Switches with Enable Inputs and Address Latching

General Description

The MAX4530/MAX4531/MAX4532 are low-voltage, CMOS analog ICs configured as an 8-channel multiplexer (mux) (MAX4530), two 4-channel muxes (MAX4531), and three single-pole/double-throw switches (MAX4532). These devices are pin compatible with the industry-standard 74HC4351/74HC4352/74HC4353. All devices have two complementary switch-enable inputs and address latching.

The MAX4530/MAX4531/MAX4532 operate from a single supply of +2V to +12V, or from dual supplies of ±2V to ±6V. On-resistance (150Ω max) is matched between switches to 8Ω max. Each switch can handle rail-to-rail analog signals. Off-leakage current is only 1nA at T_A = +25°C and 50nA at T_A = +85°C.

All digital inputs have 0.8V and 2.4V logic thresholds, ensuring both TTL- and CMOS-logic compatibility when using ±5V or a single +5V supply.

Applications

- Battery-Operated Equipment
- Data Acquisition
- Test Equipment
- Avionics
- Networking
- ATE Equipment
- Audio-Signal Routing

Features

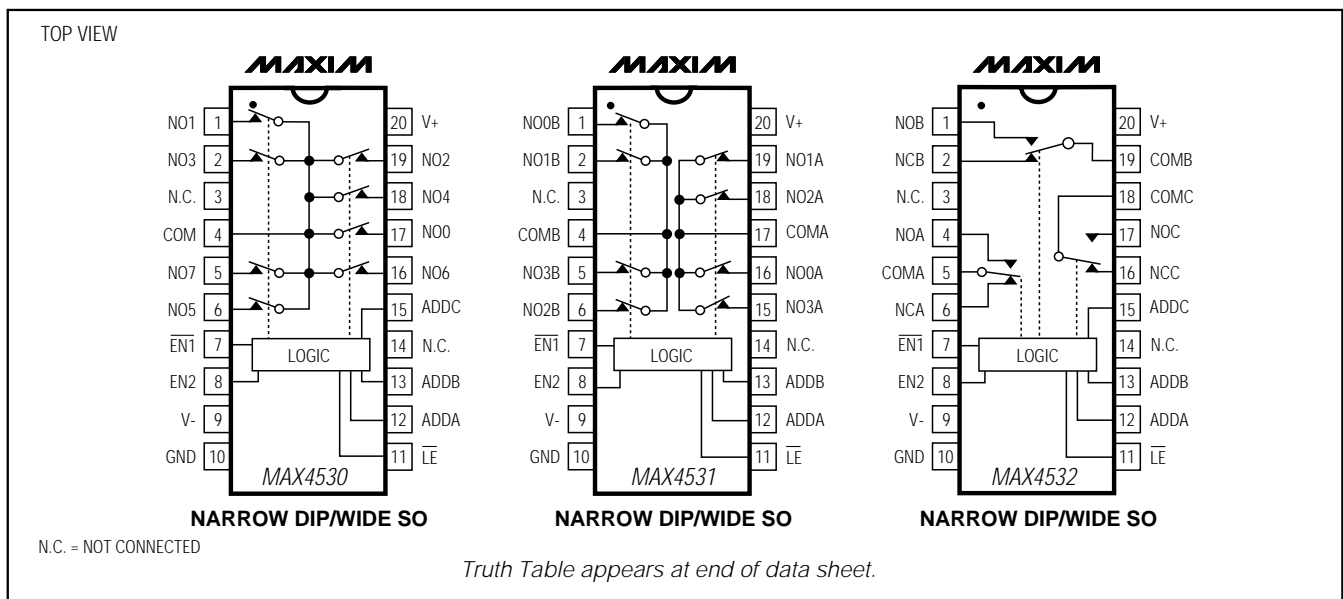
- ◆ Pin Compatible with 74HC4351/74HC4352/74HC4353
- ◆ ±2.0V to ±6V Dual Supplies
+2.0V to +12V Single Supply
- ◆ 75Ω Signal Paths with ±5V Supplies
150Ω Signal Paths with +5V Supply
- ◆ Rail-to-Rail Signal Handling
- ◆ t_{ON} and t_{OFF} = 150ns and 120ns at ±4.5V
- ◆ <1μW Power Consumption
- ◆ >2kV ESD Protection per Method 3015.7
- ◆ TTL/CMOS-Compatible Inputs
- ◆ Small, 20-Pin SSOP/SO/DIP Packages

Ordering Information

PART	TEMP. RANGE	PIN-PACKAGE
MAX4530CPP	0°C to +70°C	20 Plastic DIP
MAX4530CWP	0°C to +70°C	20 SO
MAX4530CAP	0°C to +70°C	20 SSOP
MAX4530C/D	0°C to +70°C	Dice*

Ordering Information continued on last page.
* Contact factory for availability.

Pin Configurations



MAX4530/MAX4531/MAX4532



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ABSOLUTE MAXIMUM RATINGS

Voltages Referenced to V-

V+-0.3 to +13V

Voltage into Any Terminal (Note 1)

or ±20mA (whichever occurs first)-0.3 to (V+ + 0.3V)

Continuous Current into Any Terminal.....±20mA

Peak Current, NO, NC, or COM₁

(pulsed at 1ms, 10% duty cycle).....±40mA

ESD per Method 3015.7>2000V

Continuous Power Dissipation (T_A = +70°C)

Plastic DIP (derate 11.11mW/°C above +70°C)889mW

SO (derate 10.00mW/°C above +70°C)800mW

SSOP (derate 8.00mW/°C above +70°C)640mW

Operating Temperature Ranges

MAX453_C_P0°C to +70°C

MAX453_E_P-40°C to +85°C

Storage Temperature Range-65°C to +150°C

Lead Temperature (soldering, 10sec)+300°C

Note 1: Voltages exceeding V+ or V- on any signal terminal are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Dual Supplies

(V+ = +5V ±10%, V- = -5V ±10%, GND = 0V, V_{ADD_H} = V_{EN_H} = V_{CE} = 2.4V, V_{ADD_L} = V_{EN_L} = 0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS	
SWITCH								
Analog-Signal Range	V _{COM} , V _{NO} , V _{NC}	(Note 3)		V-		V+	V	
Channel On-Resistance	R _{ON}	I _{NO} = 2mA, V _{COM} = ±3.5V, V+ = +4.5V, V- = -4.5V	T _A = +25°C	45	75		Ω	
			T _A = T _{MIN} to T _{MAX}			100		
On-Resistance Matching Between Channels (Note 4)	ΔR _{ON}	I _{NO} = 2mA, V _{COM} = ±4.5V, V+ = +4.5V, V- = -4.5V	T _A = +25°C	1	8		Ω	
			T _A = T _{MIN} to T _{MAX}			12		
On-Resistance Flatness (Note 5)	R _{FLAT(ON)}	I _{NO} = 2mA; V _{COM} = -3V, 0V, +3V; V+ = 5V; V- = -5V	T _A = +25°C	4	10		Ω	
			T _A = T _{MIN} to T _{MAX}			13		
NO-Off Leakage Current (Note 6)	I _{NO(OFF)}	V _{NO} = ±4.5V, V _{COM} = ∓4.5V, V+ = 5.5V, V- = -5.5V	T _A = +25°C	-1	0.01	1	nA	
			T _A = T _{MIN} to T _{MAX}			10		
COM-Off Leakage Current (Note 6)	I _{COM(OFF)}	V _{COM} = ±4.5V, V _{NO} = ∓4.5V, V+ = 5.5V, V- = -5.5V	MAX4530	T _A = +25°C	-2	0.01	2	nA
			MAX4530	T _A = T _{MIN} to T _{MAX}			100	
		MAX4531/ MAX4532	T _A = +25°C	-1	0.01	1		
			T _A = T _{MIN} to T _{MAX}			50		
COM-On Leakage Current (Note 6)	I _{COM(ON)}	V _{COM} = ±4.5V, V+ = 5.5V, V- = -5.5V	MAX4530	T _A = +25°C	-2	0.01	2	nA
			MAX4530	T _A = T _{MIN} to T _{MAX}			100	
		MAX4531/ MAX4532	T _A = +25°C	-1	0.01	1		
			T _A = T _{MIN} to T _{MAX}			50		

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ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

(V+ = +5V ±10%, V- = -5V ±10%, GND = 0V, VADD_H = VEN_H = VLE = 2.4V, VADD_L = VEN_L = 0.8V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP (Note 2)	MAX	UNITS
DIGITAL LOGIC INPUT						
Logic High Threshold	VADD_H, VEN_H, VLE		TA = TMIN to TMAX		1.5 2.4	V
Logic Low Threshold	VADD_L, VEN_L, VLE		TA = TMIN to TMAX		0.8 1.5	V
Input Current with Input Voltage High	IADD_H, IEN_H, ILE	VADD_H = 2.4V, VADD_L = 0.8V	-0.1	0.01	0.1	µA
Input Current with Input Voltage Low	IADD_L, IEN_L, ILE	VADD_H = 2.4V, VADD_L = 0.8V	-0.1		0.1	µA
SUPPLY						
Power-Supply Range	V+, V-		±2.0		±6	V
Positive Supply Current	I+	VEN_ = VADD_ = VLE = 0V/V+, V+ = 5.5V, V- = -5.5V	TA = +25°C		-1 0.001 1	µA
			TA = TMIN to TMAX		-10 10	
Negative Supply Current	I-	VEN_ = VADD_ = VLE = 0V/V+, V+ = 5.5V, V- = -5.5V	TA = +25°C		-1 0.001 1	µA
			TA = TMIN to TMAX		-10 10	
IGND Supply Current	IGND	VEN_ = VADD_ = VLE = 0V/V+, V+ = 5.5V, V- = -5.5V	TA = +25°C		-1 1	µA
			TA = TMIN to TMAX		-10 10	
DYNAMIC						
Transition Time	tTRANS	Figure 1	TA = +25°C		60 150	ns
			TA = TMIN to TMAX		250	
Break-Before-Make Interval	tBBM	Figure 3	TA = +25°C		4 10	ns
Enable Turn-On Time	tON(EN)	Figure 2	TA = +25°C		10 150	ns
			TA = TMIN to TMAX		250	
Enable Turn-Off Time	tOFF(EN)	Figure 2	TA = +25°C		40 100	ns
			TA = TMIN to TMAX		150	
Setup Time, Channel Select to Latch Enable	ts	Figure 4	TA = +25°C		50	ns
			TA = TMIN to TMAX		60	
Hold Time, Latch Enable to Channel Select	tH	Figure 6	TA = +25°C		0	ns
			TA = TMIN to TMAX		0	
Pulse Width, Latch Enable	tmpw	Figure 5	TA = +25°C		60	ns
			TA = TMIN to TMAX		70	
Charge Injection (Note 3)	Q	CL = 1nF, VNO = 0V, Figure 6	TA = +25°C		1.5 5	pC
Off Isolation (Note 7)	VISO	VEN2 = 0V, RL = 1kΩ, f = 1MHz	TA = +25°C		-65	dB
Crosstalk Between Channels	VCT	VEN1 = 0V, VEN2 = 2.4V, f = 1MHz, VGEN = 1Vp-p, RL = 1kΩ	TA = +25°C		-92	dB

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ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

(V₊ = +5V ±10%, V₋ = -5V ±10%, GND = 0V, V_{ADD_H} = V_{EN_H} = V_{LE} = 2.4V, V_{ADD_L} = V_{EN_L} = 0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
Distortion, THD			T _A = +25°C		0.025		
Logic Input Capacitance	C _{IN}	f = 1MHz	T _A = +25°C		3		pF
NO-Off Capacitance	C _{NO(OFF)}	f = 1MHz, V _{EN} = V _{COM} = 0V	T _A = +25°C		3		pF
COM-Off Capacitance	C _{COM(OFF)}	f = 1MHz, V _{EN2} = V _{COM} = 0V	MAX4530	T _A = +25°C	15		pF
			MAX4531		9		
			MAX4532		6		
COM-On Capacitance	C _{COM(ON)}	f = 1MHz, V _{EN1} = V _{COM} = 0V, V _{EN2} = 2.4V	MAX4530	T _A = +25°C	26		pF
			MAX4531		20		
			MAX4532		17		

ELECTRICAL CHARACTERISTICS—Single +5V Supply

(V₊ = +5V ±10%, V₋ = 0V, GND = 0V, V_{ADD_H} = V_{EN_H} = V_{LE} = 2.4V, V_{ADD_L} = V_{EN_L} = 0.8V, T_A = T_{MIN} to T_{MAX}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2)	MAX	UNITS
SWITCH							
Analog Signal Range	V _{COM} , V _{NO}	(Note 3)		0		V ₊	V
On-Resistance	R _{ON}	I _{NO} = 1mA, V _{COM} = 3.5V, V ₊ = 4.5V	T _A = +25°C	80	150		Ω
			T _A = T _{MIN} to T _{MAX}		200		
On-Resistance Matching Between Channels (Notes 3, 4)	ΔR _{ON}	I _{NO} = 1mA, V _{COM} = 3.5V, V ₊ = 4.5V	T _A = +25°C	2	15		Ω
			T _A = T _{MIN} to T _{MAX}		20		
On-Resistance Flatness	R _{FLAT}	I _{NO} = 1mA; V _{COM} = 3V, 2V, 1V; V ₊ = 5V	T _A = +25°C		10		Ω
NO-Off Leakage Current (Note 8)	I _{NO(OFF)}	V _{NO} = 4.5V; V _{COM} = 4.5V, 1V; V ₊ = 5.5V	T _A = +25°C	-1	1		nA
			T _A = T _{MIN} to T _{MAX}	-10	10		
COM-Off Leakage Current (Note 8)	I _{COM(OFF)}	V _{COM} = 4.5V, 1V; V _{NO} = 1V, 4.5V; V ₊ = 5.5V	MAX4530	T _A = +25°C	-2	2	nA
			MAX4531/ MAX4532	T _A = T _{MIN} to T _{MAX}	-100	100	
				T _A = +25°C	-1	1	
COM-On Leakage Current (Note 8)	I _{COM(ON)}		MAX4530	T _A = +25°C	-2	2	nA
				T _A = T _{MIN} to T _{MAX}	-100	100	
			MAX4531/ MAX4532	T _A = +25°C	-1	1	
				T _A = T _{MIN} to T _{MAX}	-50	50	

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ELECTRICAL CHARACTERISTICS—Single +5V Supply (continued)

(V+ = +5V ±10%, V- = 0V, GND = 0V, VADD_H = VEN_H = VLE = 2.4V, VADD_L = VEN_L = 0.8V, TA = TMIN to TMAX, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP (Note 2)	MAX	UNITS
DIGITAL LOGIC INPUT						
Logic-High Threshold	$V_{ADD_H}, V_{EN_H}, V_{LE}$		TA = TMIN to TMAX		1.5 2.4	V
Logic-Low Threshold	$V_{ADD_L}, V_{EN_L}, V_{LE}$		TA = TMIN to TMAX		0.8 1.5	V
Input Current with Input Voltage High	$I_{ADD_H}, I_{EN_H}, I_{LE}$	VH = 2.4V, VL = 0.8V			-0.1 0.1	µA
Input Current with Input Voltage Low	$I_{ADD_L}, I_{EN_L}, I_{LE}$	VH = 2.4V, VL = 0.8V			-0.1 0.1	µA
SUPPLY						
Power-Supply Range					2.0 12	V
Positive Supply Current	I+	VEN_ = VADD = VLE = 0V, V+; V+ = 5.5V; V- = 0V	TA = +25°C		-1.0 1.0	µA
			TA = TMIN to TMAX		-10 10	
Negative Supply Current	I-	VEN_ = VADD = VLE = 0V, V+; V+ = 5.5V; V- = 0V	TA = +25°C		-1.0 1.0	µA
			TA = TMIN to TMAX		-10 10	
IGND Supply Current	IGND	VEN_ = VADD = VLE = 0V, V+; V+ = 5.5V; V- = 0V	TA = +25°C		-1.0 1.0	µA
			TA = TMIN to TMAX		-10 10	
DYNAMIC						
Transition Time	tTRANS	Figure 1, VNO = 3V	TA = +25°C		90 200	ns
			TA = TMIN to TMAX		250	
Break-Before-Make Interval	tBBM	Figure 3 (Note 3)	TA = +25°C		10 20	ns
Enable Turn-On Time (Note 3)	tON(EN)	Figure 2	TA = +25°C		100 200	ns
			TA = TMIN to TMAX		250	
Enable Turn-Off Time (Note 3)	tOFF(EN)	Figure 3	TA = +25°C		40 100	ns
			TA = TMIN to TMAX		125	
Set-Up Time, Channel Select to Latch Enable	ts	Figure 7	TA = +25°C		50	ns
			TA = TMIN to TMAX		60	
Hold Time, Latch Enable to Channel Select	tH	Figure 7	TA = +25°C		0	ns
			TA = TMIN to TMAX		0	
Pulse Width, Latch Enable	tmpw	Figure 7	TA = +25°C		60	ns
			TA = TMIN to TMAX		70	
Charge Injection (Note 3)	Q	Figure 7, CL = 1nF, VNO = 0V	TA = +25°C		1.5 5	pC

MAX4530/MAX4531/MAX4532

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ELECTRICAL CHARACTERISTICS—Single +3V Supply

($V_+ = +2.7V$ to $3.6V$, $V_- = 0V$, $GND = 0V$, $V_{ADD_H} = V_{EN_H} = V_{CE} = 2.4V$, $V_{ADD_L} = V_{EN_L} = 0.5V$, $T_A = T_{MIN}$ to T_{MAX} , unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	MIN	TYP (Note 2)	MAX	UNITS
SWITCH						
Analog Signal Range	V_{ANALOG}	(Note 3)	0		V_+	V
On-Resistance	R_{ON}	$I_{NO} = 1mA$, $V_{COM} = 1.5V$, $V_+ = 2.7V$	$T_A = +25^\circ C$	220	500	Ω
			$T_A = T_{MIN}$ to T_{MAX}		600	
DYNAMIC						
Transition Time (Note 3)	t_{TRANS}	Figure 1, $V_{IN} = 2.4V$, $V_{NO1} = 1.5V$, $V_{NO8} = 0V$	$T_A = +25^\circ C$	150	350	ns
Enable Turn-On Time (Note 3)	$t_{ON(EN)}$	Figure 3, $V_{INH} = 2.4V$, $V_{INL} = 0V$, $V_{NO1} = 1.5V$	$T_A = +25^\circ C$	150	350	ns
Enable Turn-Off Time (Note 3)	$t_{OFF(EN)}$	Figure 3, $V_{INH} = 2.4V$, $V_{INL} = 0V$, $V_{NO1} = 1.5V$	$T_A = +25^\circ C$	60	150	ns
Set-Up Time, Channel Select to Latch Enable)	t_s	Note 3	$T_A = +25^\circ C$	100		ns
Hold Time, Latch Enable to Channel Select	t_H	Note 3	$T_A = +25^\circ C$	0		ns
Pulse Width, Latch Enable	t_{MPW}	Note 3	$T_A = +25^\circ C$	120		ns

Note 2: The algebraic convention, where the most negative value is a minimum and the most positive value a maximum, is used in this data sheet.

Note 3: Guaranteed by design.

Note 4: $\Delta R_{ON} = R_{ON(max)} - R_{ON(min)}$.

Note 5: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges, i.e., $V_{NO} = 3V$ to $0V$ and $0V$ to $-3V$.

Note 6: Leakage parameters are 100% tested at maximum rated hot operating temperature, and guaranteed by correlation at $T_A = +25^\circ C$.

Note 7: Worst-case isolation is on channel 4 because of its proximity to the COM pin. Off isolation = $20 \log V_{COM} / V_{NO}$, V_{COM} = output, V_{NO} = input to off switch.

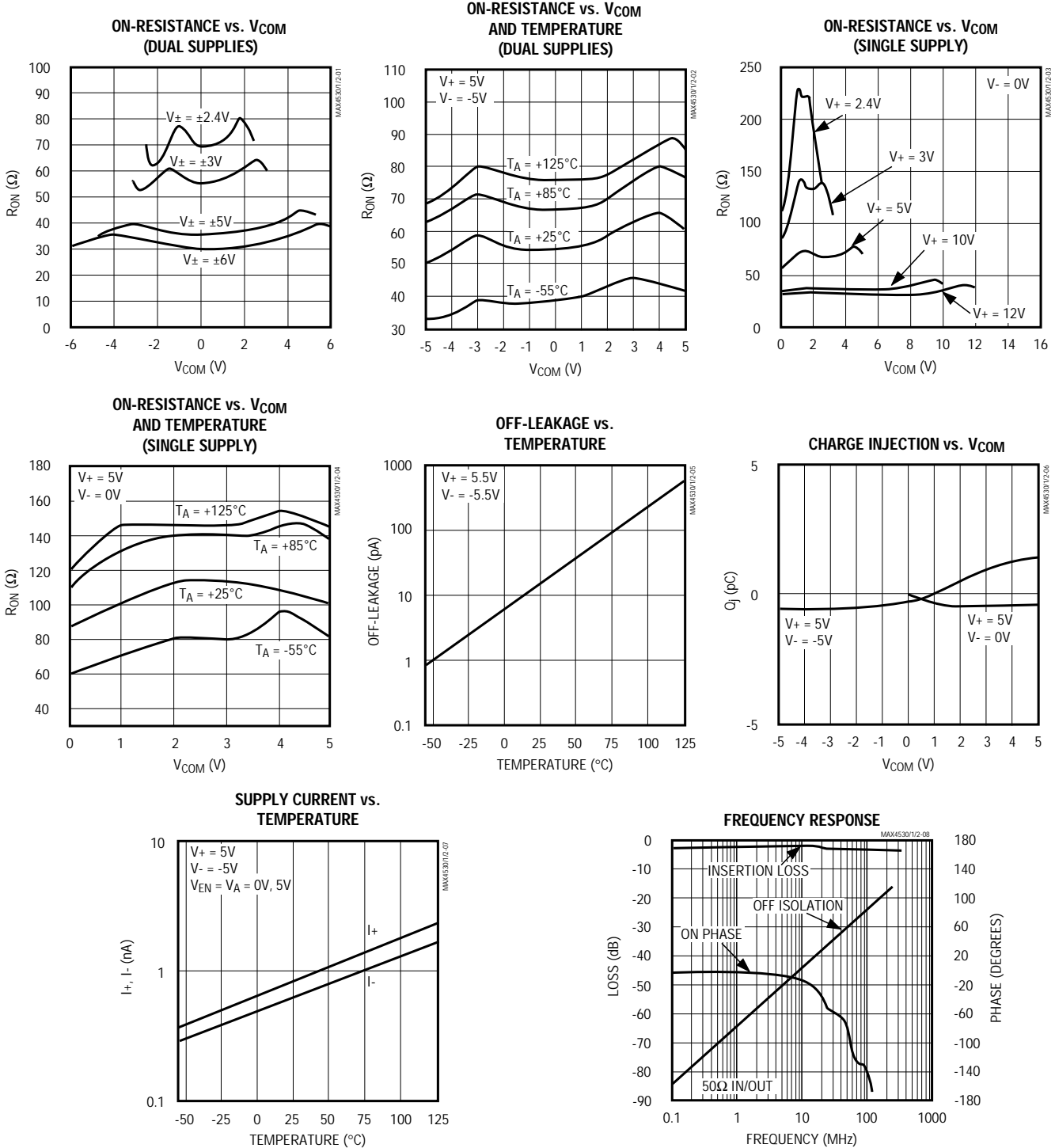
Note 8: Leakage testing at single supply is guaranteed by correlation testing with dual supplies.

Low-Voltage, CMOS Analog Multiplexers/Switches with Enable Inputs and Address Latching

Typical Operating Characteristics

($T_A = +25^\circ\text{C}$, unless otherwise noted.)

MAX4530/MAX4531/MAX4532



Low-Voltage, CMOS Analog Multiplexers/Switches with Enable Inputs and Address Latching

Pin Description

PIN			NAME	FUNCTION
MAX4530	MAX4531	MAX4532		
17, 1, 19, 2, 18, 6, 16, 5	—	—	NO0–NO7	Analog Switch Inputs 0–7
—	1, 2, 6, 5	—	NO0B–NO3B	Analog Switch “B” Inputs 0–3
—	—	1	NOB	Analog Switch “B” Normally Open Input
—	—	2	NCB	Analog Switch “B” Normally Closed Input
3, 14	3, 14	3, 14	N.C.	Not Internally Connected
4	—	—	COM	Analog Switch Common
—	4	19	COMB	Analog Switch “B” Common
—	—	4	NOA	Analog Switch “A” Normally Open Input
—	17	5	COMA	Analog Switch “A” Common
—	—	6	NCA	Analog Switch “A” Normally Closed Input
7	7	7	EN1	Enable Logic Input #1 (see <i>Truth Table</i>).
8	8	8	EN2	Enable Logic Input #2 (see <i>Truth Table</i>).
9	9	9	V-	Negative Analog Supply Voltage Input. Connect to GND for single supply operation.
10	10	10	GND	Negative Digital Supply Voltage Input. Connect to digital ground. (Analog signals have no ground)
11	11	11	LE	Address Latch Logic Input (see <i>Truth Table</i>).
12	12	12	ADDA	Address “A” Logic Input (see <i>Truth Table</i>).
13	13	13	ADDB	Address “B” Logic Input (see <i>Truth Table</i>).
15	—	15	ADDC	Address “C” Logic Input (see <i>Truth Table</i>).
—	16, 19, 18, 15	—	NO0A–NO3A	Analog Switch “A” Inputs 0–3
—	—	16	NCC	Analog Switch “C” Normally Closed Input
—	—	17	NOC	Analog Switch “C” Normally Open Input
—	—	18	COMC	Analog Switch “C” Common
20	20	20	V+	Positive Analog and Digital Supply-Voltage Input

NO_, NC_ and COM_ pins are identical and interchangeable. Either may be considered as an input or output; signals pass equally well in both directions.

Low-Voltage, CMOS Analog Multiplexers/Switches with Enable Inputs and Address Latching

Applications Information

Power-Supply Considerations

Overview

The MAX4530/MAX4531/MAX4532 construction is typical of most CMOS analog switches. They have three supply pins: V+, V-, and GND. V+ and V- drive the internal CMOS switches and set the limits of the analog voltage on any switch. Reverse ESD-protection diodes are internally connected between each analog-signal pin and both V+ and V-. One of these diodes conducts if any analog signal exceeds V+ or V-. During normal operation, these and other reverse-biased ESD diodes leak, forming the only current drawn from V+ or V-.

Virtually all of the analog leakage current comes from the ESD diodes. Although the ESD diodes on a given signal pin are identical and therefore fairly well balanced, they are reverse biased differently. Each is biased by either V+ or V- and the analog signal. This means their leakages vary as the signal varies. The difference in the two diode leakages to the V+ and V- pins constitutes the analog-signal-path leakage current. All analog leakage current flows between each pin and one of the supply terminals, not to the other switch terminal. For this reason, both sides of a given switch can show leakage currents of either the same or opposite polarity.

The analog-signal paths and GND are not connected.

V+ and GND power the internal logic and logic-level translators, and set both the input and output logic limits. The logic-level translators convert the logic levels into switched V+ and V- signals to drive the analog signals' gates. This drive signal is the only connection between the logic supplies and signals and the analog supplies. V+ and V- have ESD-protection diodes to GND.

The logic-level thresholds are TTL/CMOS compatible when V+ = +5V. As V+ rises, the threshold increases slightly, so when V+ reaches +12V, the threshold is about 3.1V—above the TTL guaranteed, high-level minimum of 2.8V, but still compatible with CMOS outputs.

Bipolar Supplies

The MAX4530/MAX4531/MAX4532 operate with bipolar supplies between $\pm 2.0\text{V}$ and $\pm 6\text{V}$. The V+ and V- supplies need not be symmetrical, but their sum cannot exceed the +13V absolute maximum rating.

Single Supply

The MAX4530/MAX4531/MAX4532 operate from a single supply between +2V and +12V when V- is connected to GND. All of the bipolar precautions must be observed. At room temperature, they actually work with a single supply at, near, or below +1.7V, although as supply voltage decreases, switch on-resistance and switching times become very high.

High-Frequency Performance

In 50 Ω systems, signal response is reasonably flat up to 50MHz (see *Typical Operating Characteristics*). Above 20MHz, the on response has several minor peaks that are highly layout dependent. The problem is not in turning the switch on, but in turning it off. The off-state switch acts like a capacitor and passes higher frequencies with less attenuation. At 10MHz, off isolation is about -65dB in 50 Ω systems, becoming worse (approximately 20dB per decade) as frequency increases. Higher circuit impedances also make off isolation worse. Adjacent channel attenuation is about 3dB above that of a bare IC socket, and is due entirely to capacitive coupling.

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Test Circuits/Timing Diagrams

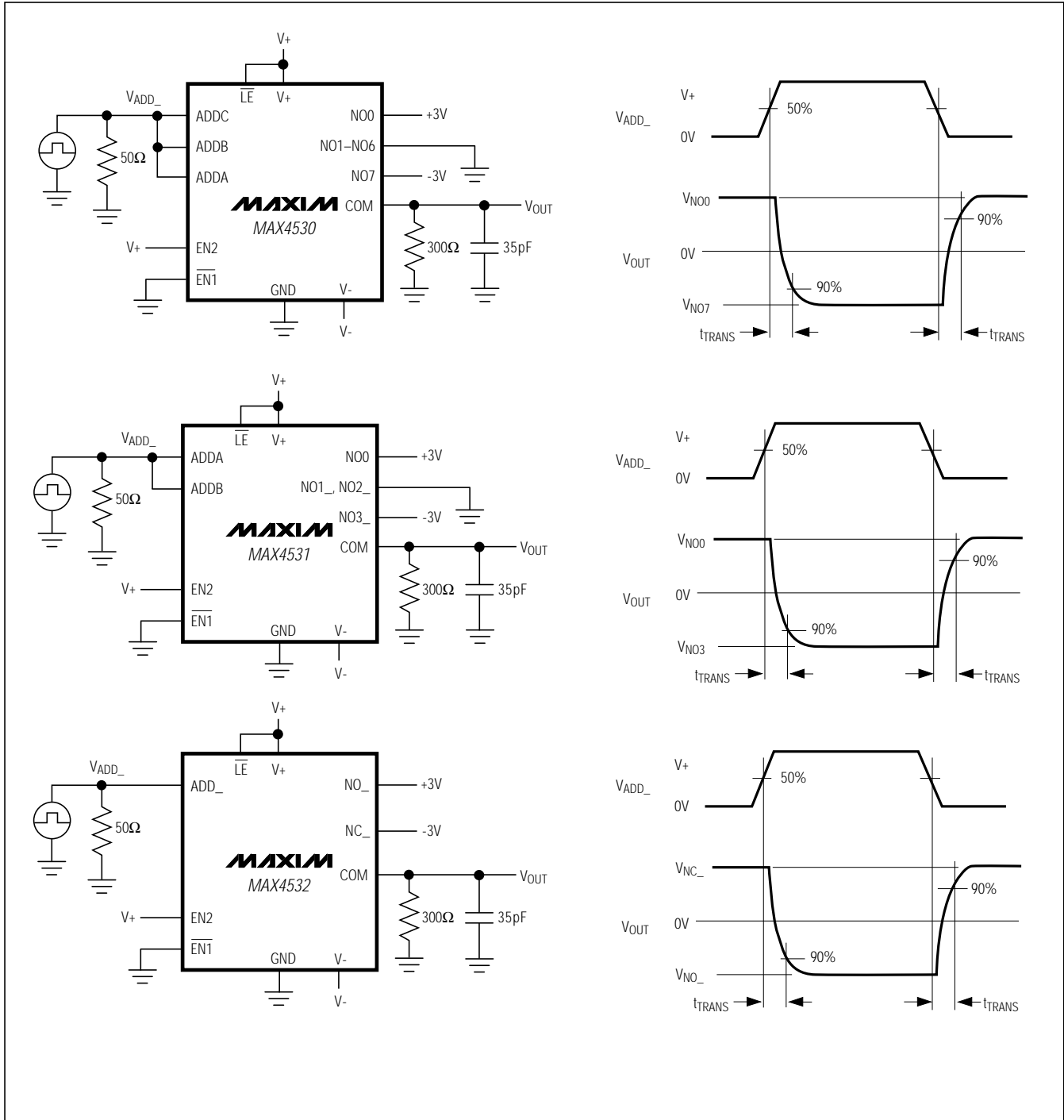


Figure 1. Address Transition Time

Low-Voltage, CMOS Analog Multiplexers/Switches with Enable Inputs and Address Latching

Test Circuits/Timing Diagrams (continued)

MAX4530/MAX4531/MAX4532

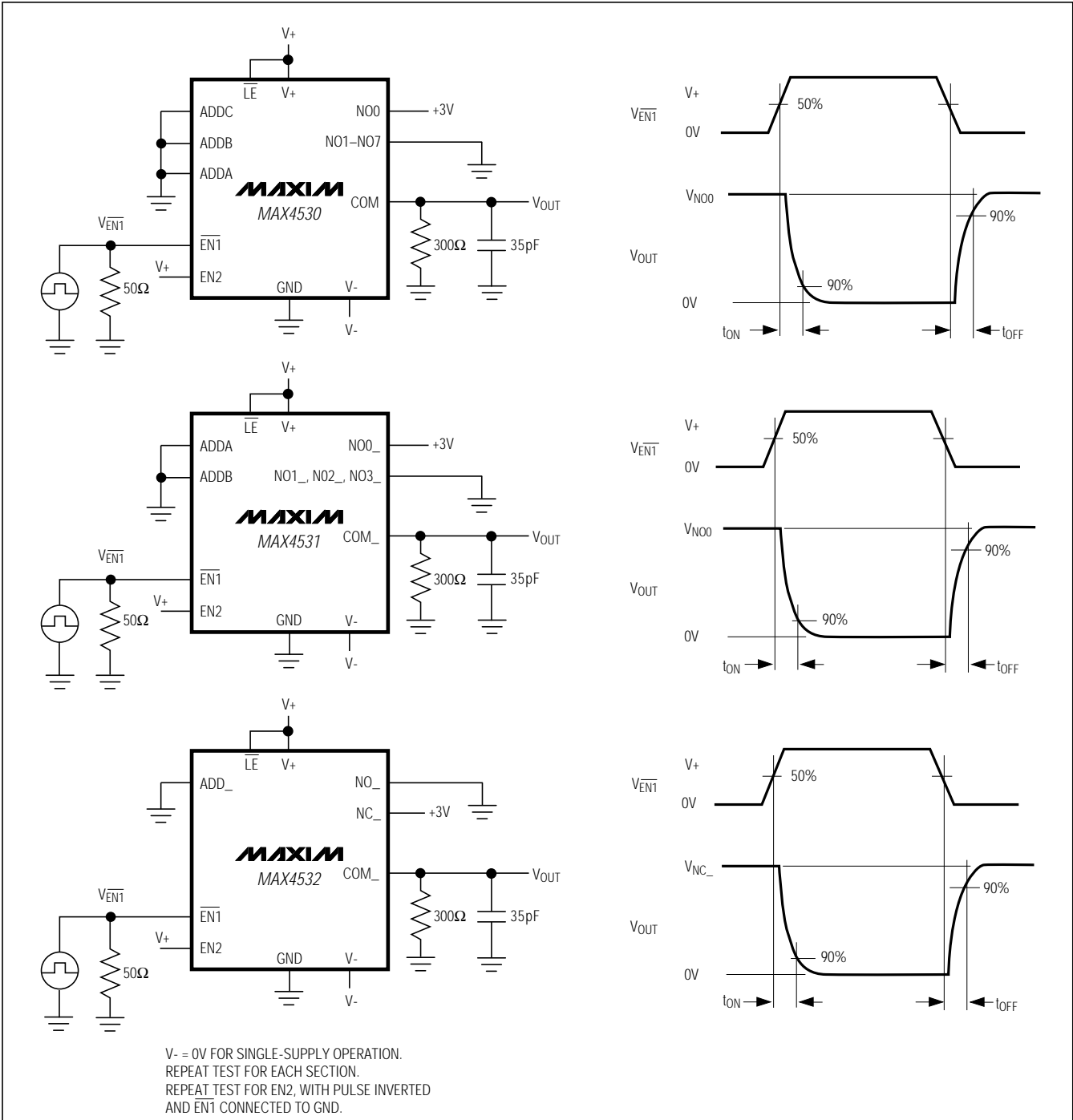


Figure 2. Enable Switching Time

Low-Voltage, CMOS Analog Multiplexers/Switches with Enable Inputs and Address Latching

Test Circuits/Timing Diagrams (continued)

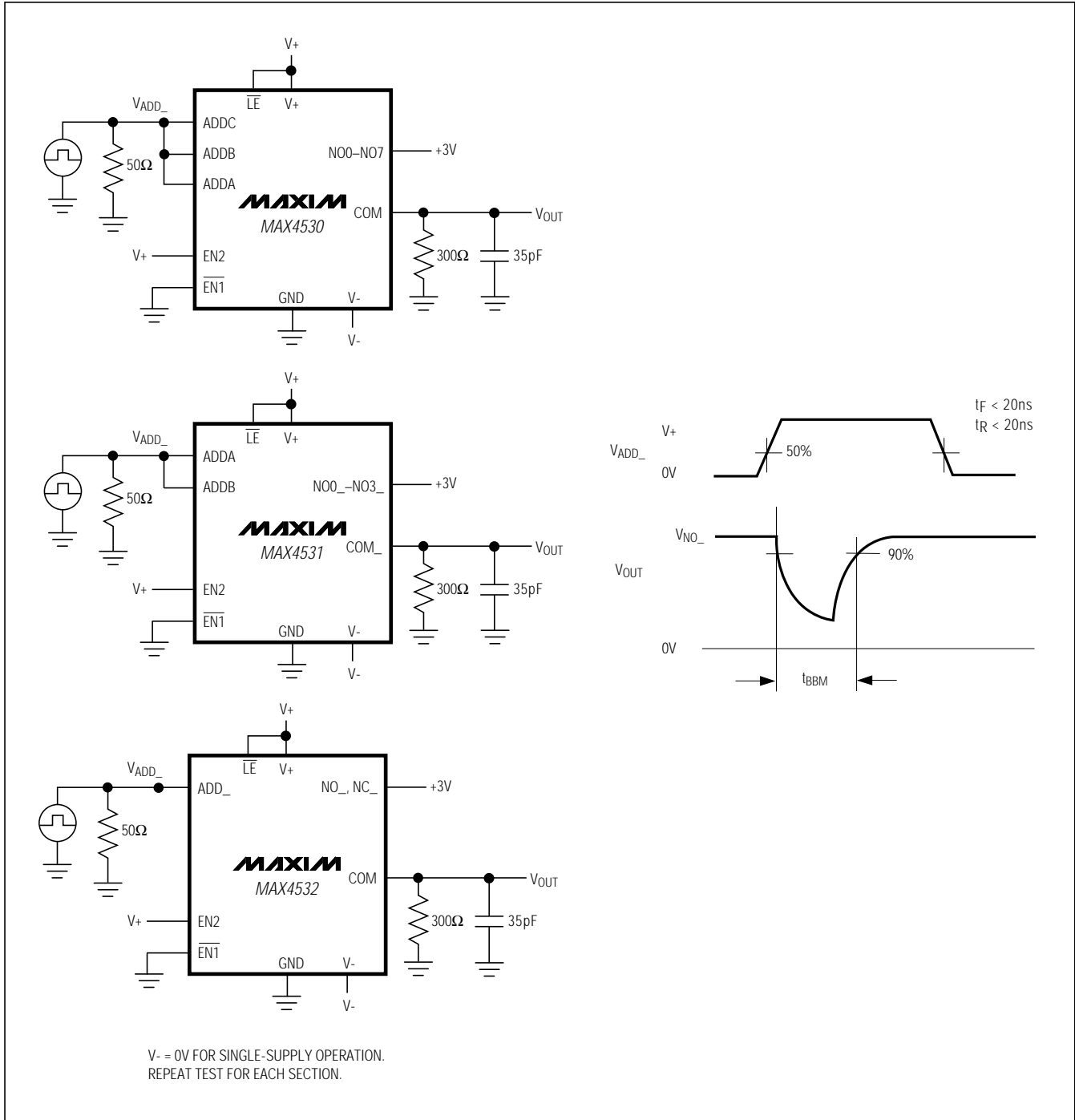


Figure 3. Break-Before-Make Interval

Low-Voltage, CMOS Analog Multiplexers/Switches with Enable Inputs and Address Latching

Test Circuits/Timing Diagrams (continued)

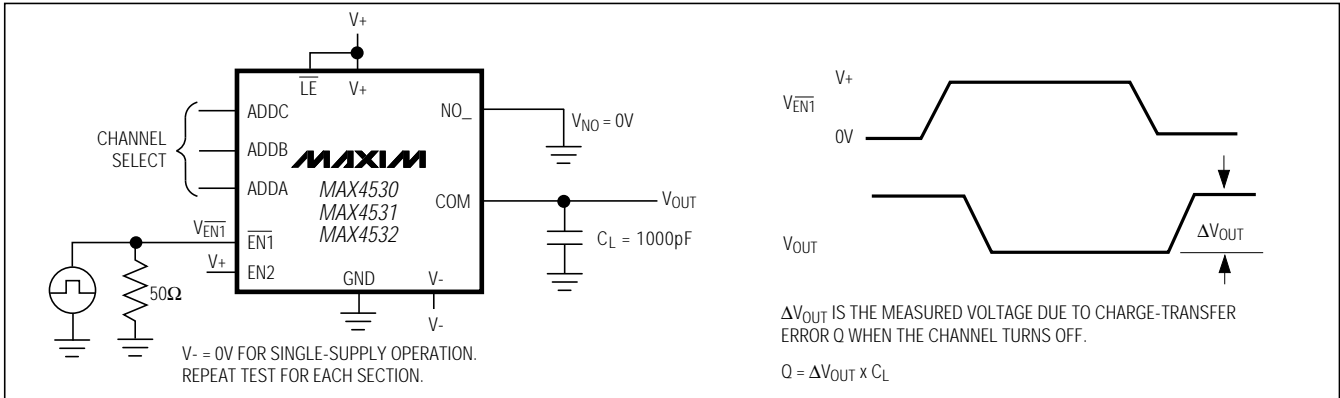


Figure 4. Charge Injection

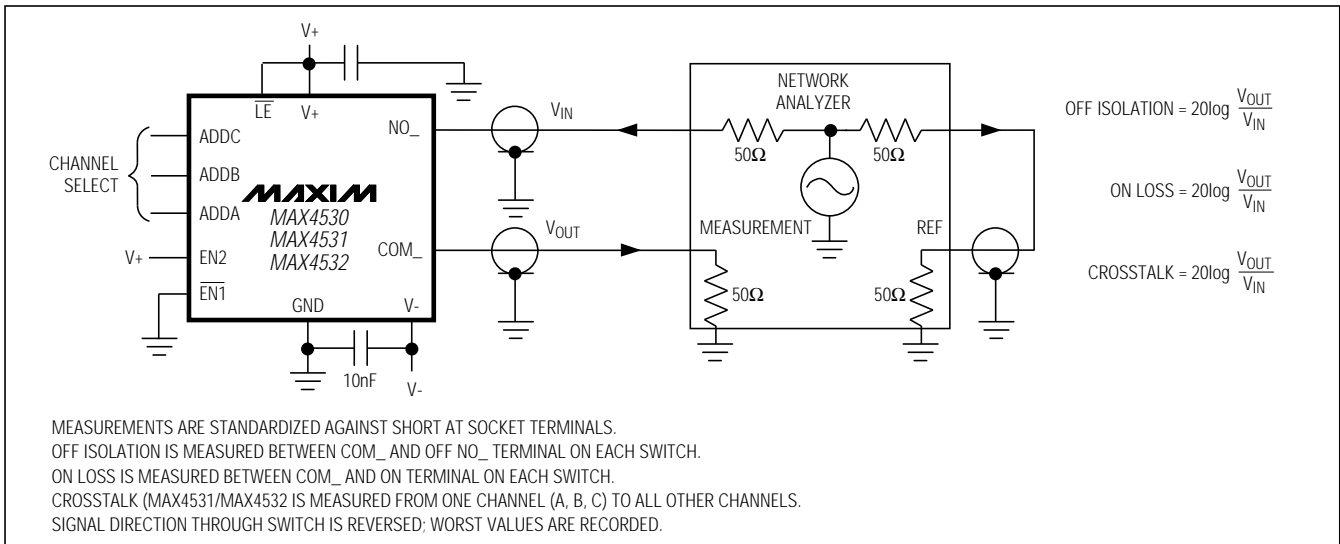


Figure 5. Off Isolation, On Loss, and Crosstalk

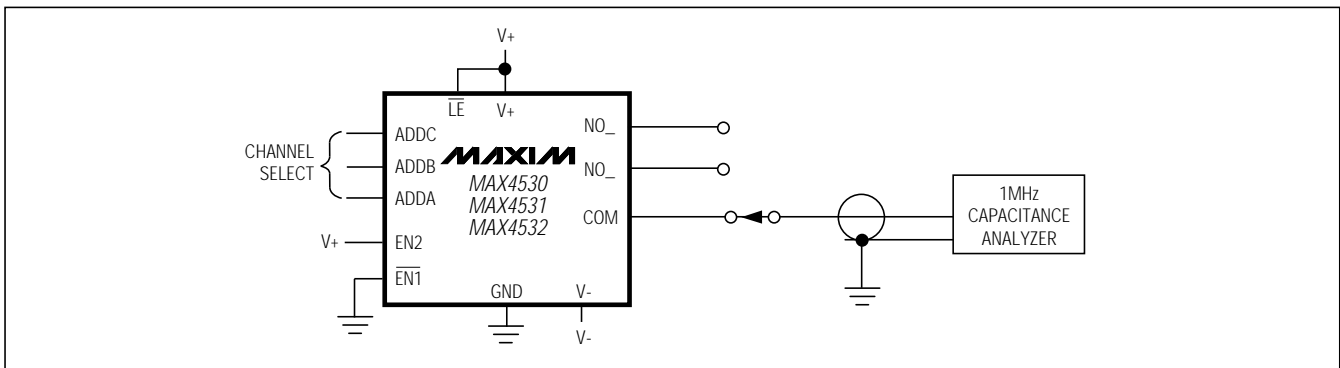


Figure 6. NO/COM Capacitance

Low-Voltage, CMOS Analog Multiplexers/Switches with Enable Inputs and Address Latching

Test Circuits/Timing Diagrams (continued)

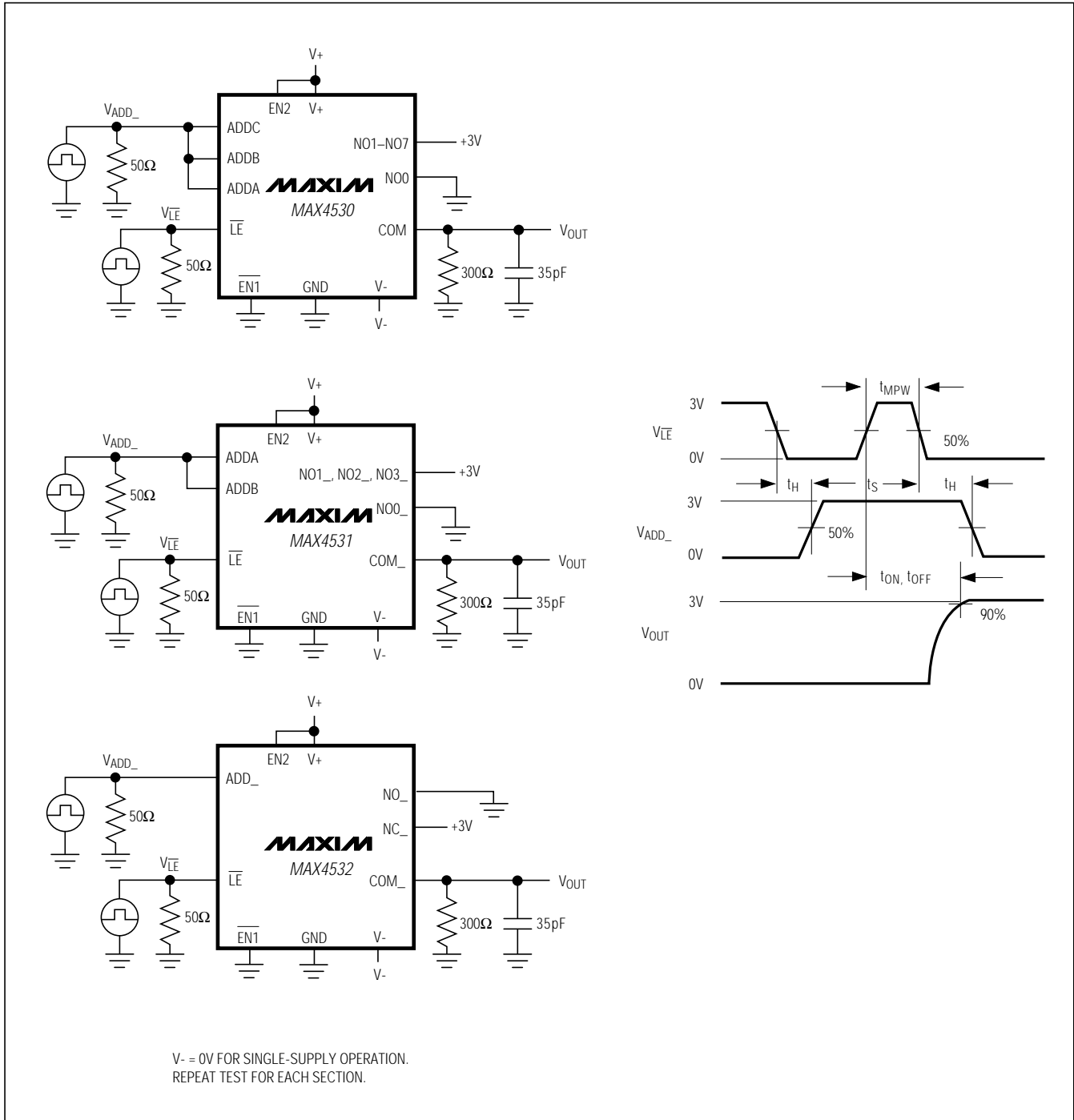


Figure 7. Setup and Hold Times, Minimum \overline{LE} Width

Low-Voltage, CMOS Analog Multiplexers/Switches with Enable Inputs and Address Latching

Truth Table/Switch Programming

\overline{LE}	EN2	\overline{ENT}	ADDRESS BITS			ON SWITCHES		
			ADDC*	ADDB	ADDA	MAX4530	MAX4531	MAX4532
0	1	0	X	X	X	Last address	Last address	Last address
X	0	X	X	X	X	All switches open	All switches open	All switches open
X	X	1	X	X	X	All switches open	All switches open	All switches open
1	1	0	0	0	0	COM-NO0	COMA-NO0A, COMB-NO0B	COMA-NCA, COMB-NCB, COMC-NCC
1	1	0	0	0	1	COM-NO1	COMA-NO1A, COMB-NO1B	COMA-NOA, COMB-NCB, COMC-NCC
1	1	0	0	1	0	COM-NO2	COMA-NO2A, COMB-NO2B	COMA-NCA, COMB-NOB, COMC-NCC
1	1	0	0	1	1	COM-NO3	COMA-NO3A, COMB-NO3B	COMA-NOA, COMB-NOB, COMC-NCC
1	1	0	1	0	0	COM-NO4	COMA-NO0A, COMB-NO0B	COMA-NCA, COMB-NCB, COMC-NOC
1	1	0	1	0	1	COM-NO5	COMA-NO1A, COMB-NO1B	COMA-NOA, COMB-NCB, COMC-NOC
1	1	0	1	1	0	COM-NO6	COMA-NO2A, COMB-NO2B	COMA-NCA, COMB-NOB, COMC-NOC
1	1	0	1	1	1	COM-NO7	COMA-NO3A, COMB-NO3B	COMA-NOA, COMB-NOB, COMC-NOC

X = Don't Care *ADDC not present on MAX4531.

Note: NO_ and COM_ pins are identical and interchangeable. Either may be considered an input or an output; signals pass equally well in either direction. \overline{LE} is independent of \overline{ENT} and EN2.

MAX4530/MAX4531/MAX4532

Low-Voltage, CMOS Analog Multiplexers/Switches with Enable Inputs and Address Latching

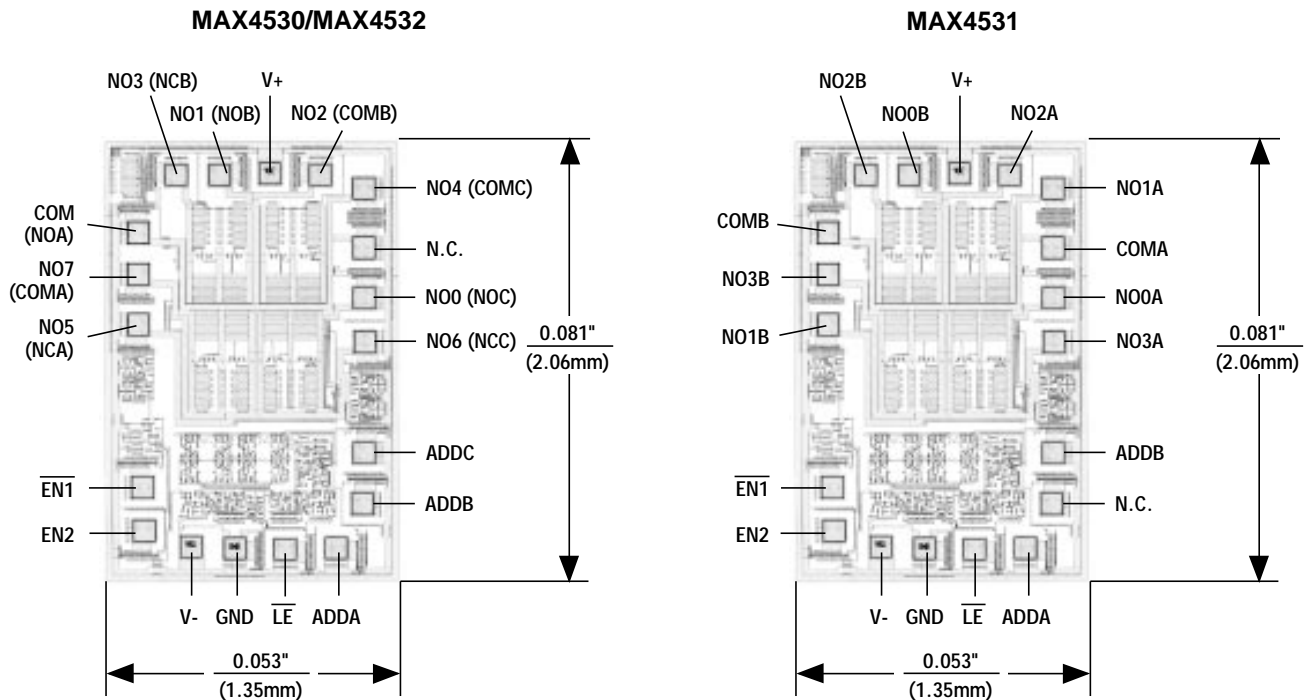
Ordering Information (continued)

PART	TEMP. RANGE	PIN-PACKAGE
MAX4530EPP	-40°C to +85°C	20 Plastic DIP
MAX4530EWP	-40°C to +85°C	20 SO
MAX4530EAP	-40°C to +85°C	20 SSOP
MAX4531 CPP	0°C to +70°C	20 Plastic DIP
MAX4531CWP	0°C to +70°C	20 SO
MAX4531CAP	0°C to +70°C	20 SSOP
MAX4531C/D	0°C to +70°C	Dice*
MAX4531EPP	-40°C to +85°C	20 Plastic DIP
MAX4531EWP	-40°C to +85°C	20 SO
MAX4531EAP	-40°C to +85°C	20 SSOP

PART	TEMP. RANGE	PIN-PACKAGE
MAX4532 CPP	0°C to +70°C	20 Plastic DIP
MAX4532CWP	0°C to +70°C	20 SO
MAX4532CAP	0°C to +70°C	20 SSOP
MAX4532C/D	0°C to +70°C	Dice*
MAX4532EPP	-40°C to +85°C	20 Plastic DIP
MAX4532EWP	-40°C to +85°C	20 SO
MAX4532EAP	-40°C to +85°C	20 SSOP

* Contact factory for availability.

Chip Topographies



() ARE FOR MAX4532

TRANSISTOR COUNT: 255

SUBSTRATE CONNECTED TO V+

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